Supertex inc.

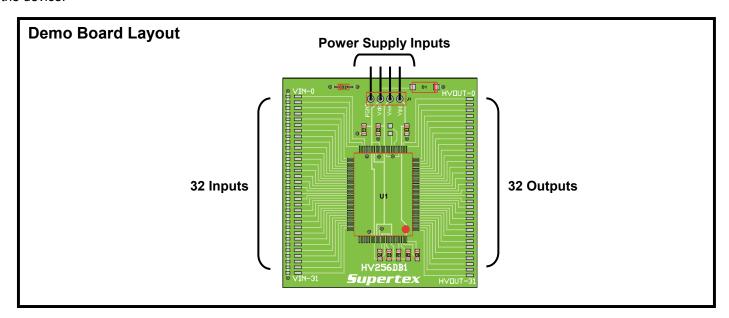
High Voltage Amplifier Array HV256DB1

Introduction

The Supertex HV256DB1 is a 32-Channel 295V amplifier array with a nominal gain of 72V/V. The purpose of the HV256DB1 is to provide a means to easily evaluate the Supertex HV256FG device. A high voltage supply, $V_{\text{PP}},$ and two low voltage supplies, V_{DD} and $V_{\text{NN}},$ are required. These connections can be made via the J1 header provided on the board. There are 32 pads on the left side of the board for the input signals and 32 pads on the right for the outputs. Be sure to follow the power up/down sequence to avoid damaging the device.

Specifications

V _{PP} , High voltage supply	300V
V _{DD} , Low voltage positive supply	6.0V to 7.5V
V _{NN} , Low voltage negative supply	-4.5V to -6.5V
V _{IN} , Input signal range	0V to 5.0V
HV _{OUT} , Output voltage swing	0V to 295V
Av, Closed loop gain	72V/V ±5%
SR, Output slew rate into 100pF load	2.0V/µs



Power Up/Down Sequence

The device can be damaged due to improper power up/down sequence. To prevent damage, please follow the acceptable power up/down sequences. Two external diodes, D1 and D2, are added in the demo board to prevent damage during power Up/Down. The first diode is a high voltage diode across V_{PP} and $V_{\text{DD}}.$ Any low current high voltage diode can be used. The second diode can be any low voltage schottky diode across V_{NN} and Gnd.

Acceptable Power Up Sequences

1) V _{PP}	$^{2)}$ V_{NN}	3) V _{DD}	4) Inputs
1) V _{DD}	2) V _{NN}	3) V _{PP}	4) Inputs

Acceptable Power Down Sequences

1) Inputs 2) V_{PP} 3) V_{DD} 4) V_{NN} 1) Inputs 2) V_{DD} 3) V_{NN} 4) V_{PP}

Inputs and Outputs

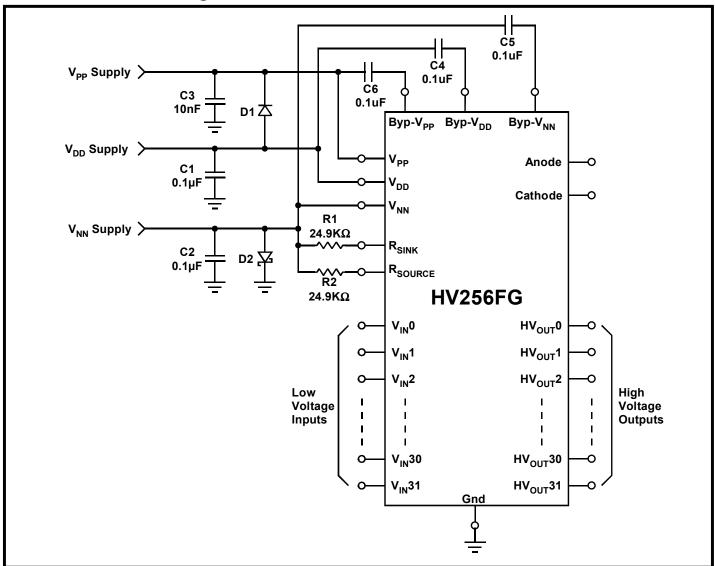
The output of the HV256FG will swing from 0V to 295V. The internal closed loop gain is set at 72V/V. An input voltage of 4.096V will give an output of 295V. Input voltages of up to 5V can be applied but will cause the amplifier to saturate.

The output current source and sink for all 32 channels can be adjusted using R1 and R2. The limit is approximately 12.5V divided by the resistor value. The demo board uses 24.9Kohm for ±500uA limiting.

Temperature Diode

The HV256FG has an integrated silicon diode to help monitor the die temperature if desired. Pin 37 is the anode and pin 36 is the cathode. Pads are available on the board for these connections.

HV256DB1 Circuit Diagram



Bill of Material

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	Description	Value	Package	Manufacturer	Part Number		
C1	X7R chip capacitor	25V, 0.1µF±10%	0805	Tecate	CMC-025104KX0805T		
C2	X7R chip capacitor	25V, 0.1µF±10%	0805	Tecate	CMC-025104KX0805T		
C3	X7R chip capacitor	500V, 0.01µF±10%	0805	Tecate	CMC-500103KX0805T		
C4	X7R chip capacitor	25V, 0.1µF±10%	0805	Tecate	CMC-025104KX0805T		
C5	X7R chip capacitor	25V, 0.1µF±10%	0805	Tecate	CMC-025104KX0805T		
C6	X7R chip capacitor	25V, 0.1µF±10%	0805	Tecate	CMC-025104KX0805T		
R1	Chip resistor	24.9Kohm, ±1%	0805	Any			
R2	Chip resistor	24.9Kohm, ±1%	0805	Any			
D1	Rectifier diode	400V, 1.0A	SMA	Diodes Inc	US1G		
D2	Schottky diode	20V, 20mA	SOD-323	Diodes Inc	SD103CWS		
U1	Amplifier array	300V	100 MQFP	Supertex	HV256FG		
J1	Right Angle 4-pin header	0.100", tin plating		Molex	22-05-3041		

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